SEMICONDUCTOR

35A 5/16" TIN CAN TYPE PRESS-FIT DIODE

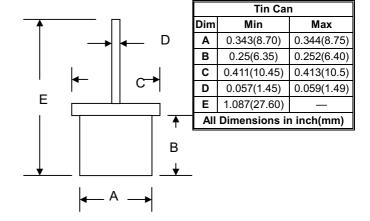
Data Sheet 2524 Rev.—

Features

- Glass Passivated Die Construction
- Low Leakage
- Low Cost
- High Surge Current Capability
- Typical IR less than 10μA

Mechanical Data

- Case: All Copper Case and Components Hermetically Sealed
- Terminals: Contact Areas Readily Solderable
- Polarity: Cathode to Case(Reverse Units Are Available Upon Request and Are Designated By An "R" Suffix, i.e. TC3502R or TC3504R)
- Polarity: Red Color Equals Standard, Black Color Equals Reverse Polarity
- Mounting Position: Any



Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	TC3500	TC3501	TC3502	TC3503	TC3504	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	VRRM VRWM VR	50	100	200	300	400	V
RMS Reverse Voltage	VR(RMS)	35	70	140	210	280	٧
Average Rectified Output Current @T _A = 150°C	lo	35					Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	400					А
Forward Voltage @I _F = 80A	VFM	1.0					V
Peak Reverse Current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 100°C		10 500					μΑ
Typical Junction Capacitance (Note 1)	Cj	300					pF
Typical Thermal Resistance Junction to Case (Note 2)	RθJC	1.0					K/W
Operating and Storage Temperature Range	TJ, TSTG	-65 to +175					°C

Note: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

2. Thermal Resistance: Junction to case, single side cooled.

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